

isc N-Channel Mosfet Transistor

STW19NM50N

- FEATURES
- Drain Current I_D= 14A@ T_C=25 $^\circ\!\!\mathrm{C}$
- Drain Source Voltage-

: V_{DSS}= 500V(Min)

- Fast Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

Switching applications

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

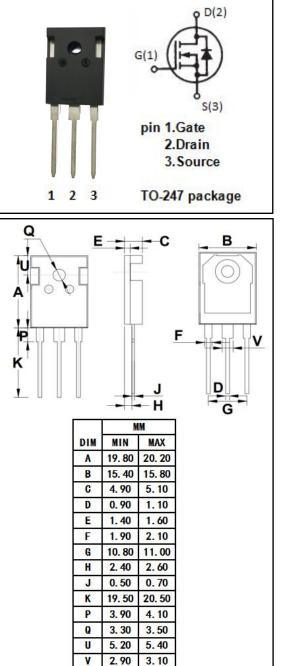
SYMBOL	PARAMETER	VALUE	UNIT					
V _{DSS}	Drain-Source Voltage	500	V					
V _{GS}	Gate-Source Voltage	±25	V					
ID	Drain Current-continuous@ T _c =25℃	14	A					
I _{DM}	Pulse Drain Current	56	A					
P _{tot}	Total Dissipation@T _C =25℃	110	W					
Tj	Max. Operating Junction Temperature	150	°C					
T _{stg}	Storage Temperature Range	-55~150	°C					
THERMAL CHARACTERISTICS								
SYMBOL	PARAMETER	МАХ	UNIT					

Thermal Resistance, Junction to Case

1.14

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°C/W



isc website: www.iscsemi.com

Rth j-c



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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25\,^\circ\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 1mA	500			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =250µA	2		4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 7A			250	mΩ
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±25V;V _{DS} =0			±100	nA
IDSS	Zero Gate Voltage Drain Current	V _{DS} = Max rating			1	μΑ
		V _{DS} = Max rating; T _C =125℃			100	
V _{SD}	Diode Forward On-Voltage	I _S = 14A ;V _{GS} = 0			1.5	V

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